2SD1745

Silicon NPN epitaxial planar type

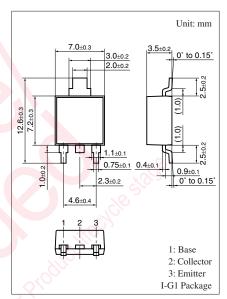
For power switching Complementary to 2SB1175

■ Features

- Low collector-emitter saturation voltage V_{CE(sat)}
- Satisfactory liniarity of forward current transfer ratio h_{FE}
- Large collector current I_C
- I type package enabling direct soldering of the radiating fin to the printed circuit board, etc. of small electronic equipment

■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V_{CBO}	130	V	
Collector-emitter voltage (Base open)	V _{CEO}	80	V	
Emitter-base voltage (Collector open)	V_{EBO}	7	V	
Collector current	I_{C}	4	A	
Peak collector current	I_{CP}	8	A	
Collector power dissipation	P _C	15	w	
$T_a = 25$ °C		1.3	40	
Junction temperature	T_{j}	150	S °C	
Storage temperature	T_{stg}	−55 ~ +150	°C	



Note) Self-supported type package is also prepared.

■ Electrical Characteristics $T_C = 25^{\circ}C \pm 3^{\circ}C$

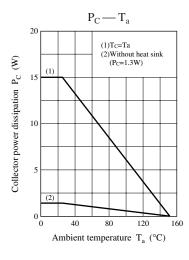
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_C = 10 \text{ mA}, I_B = 0$	80			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 100 \text{ V}, I_{E} = 0$			10	μΑ
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 5 \text{ V}, I_C = 0$			50	μΑ
Forward current transfer ratio	h _{FE1}	$V_{CE} = 2 \text{ V}, I_{C} = 0.1 \text{ A}$	45			_
<u>ainle</u>	h _{FE2} *	$V_{CE} = 2 \text{ V}, I_{C} = 1 \text{ A}$	90		260	
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 3 \text{ A}, I_B = 0.15 \text{ A}$			0.5	V
Base-emitter saturation voltage	V _{BE(sat)}	$I_C = 3 \text{ A}, I_B = 0.15 \text{ A}$			1.5	V
Transition frequency	f_T	$V_{CE} = 10 \text{ V}, I_{C} = 0.5 \text{ A}, f = 10 \text{ MHz}$		30		MHz
Turn-on time	t _{on}	$I_C = 1 A, I_{B1} = 0.1 A, I_{B2} = -0.1 A$		0.5		μs
Storage time	t _{stg}	$V_{CC} = 50 \text{ V}$		2.5		μs
Fall time	$t_{\rm f}$			0.15		μs

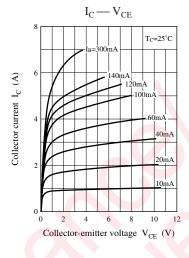
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

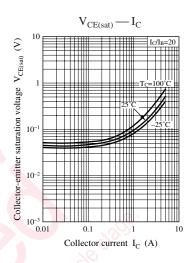
2. *: Rank classification

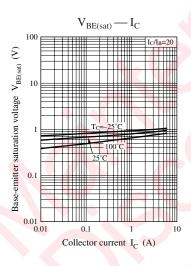
Rank	Q	Р
h _{FE1}	90 to 180	130 to 260

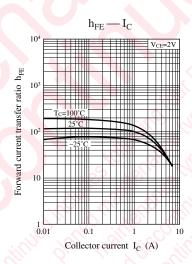
Panasonic

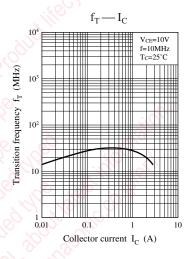


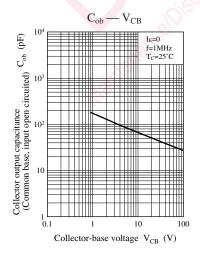


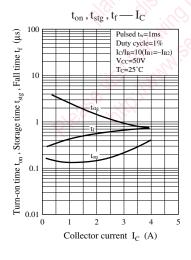


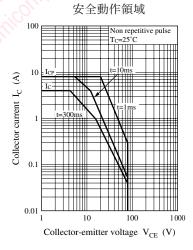




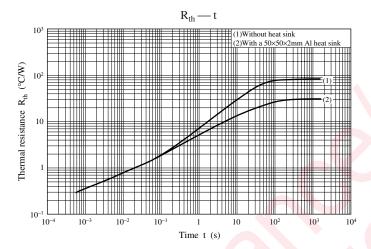








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